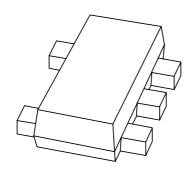
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# **BZA900AVL series**Quadruple low capacitance ESD suppressor

Product data sheet Supersedes data of 2003 Apr 15 2003 Oct 20



# Quadruple low capacitance ESD suppressor

### **BZA900AVL** series

#### **FEATURES**

- Low diode capacitance
- · Low leakage current
- SOT665 surface mount package
- Common anode configuration.

### **APPLICATIONS**

- · Communication systems
- · Computers and peripherals
- Audio and video equipment.

### **DESCRIPTION**

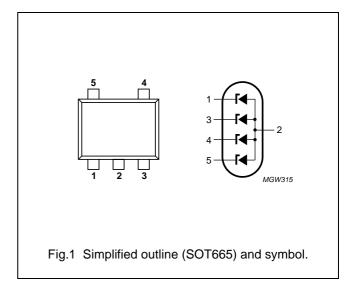
Monolithic transient voltage suppressor diode in a five lead SOT665 package for 4-bit wide ESD transient suppression.

#### **MARKING**

TYPE NUMBER	MARKING CODE
BZA956AVL	V3
BZA962AVL	V2
BZA968AVL	V1

#### **PINNING**

PIN	DESCRIPTION	
1	cathode 1	
2	common anode	
3	cathode 2	
4	cathode 3	
5	cathode 4	



#### **ORDERING INFORMATION**

TYPE NUMBER		PACKAGE	
TIPE NUMBER	NAME	DESCRIPTION	VERSION
BZA956AVL	_	plastic surface mounted package; 5 leads	SOT665
BZA962AVL	<ul> <li>plastic surface mounted package; 5 leads</li> </ul>		SOT665
BZA968AVL	_	plastic surface mounted package; 5 leads	SOT665

# Quadruple low capacitance ESD suppressor

### BZA900AVL series

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
I <sub>Z</sub>	working current	T <sub>amb</sub> = 25 °C	-	note 1	mA
I <sub>F</sub>	continuous forward current	T <sub>amb</sub> = 25 °C	-	200	mA
I <sub>FSM</sub>	non-repetitive peak forward current $t_p = 1 \text{ ms}$ ; square pulse -		_	3.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 2; see Fig.5	-	335	mW
P <sub>ZSM</sub>	non repetitive peak reverse power dissipation	square pulse; t <sub>p</sub> = 1 ms	_	6	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
ESD	electrostatic discharge	IEC 61000-4-2 (contact discharge)	15	_	kV
		HBM MIL-Std 883	10	_	kV

### **Notes**

- 1. DC working current limited by Ptot(max).
- 2. Device mounted on standard printed-circuit board.

### **ESD STANDARDS COMPLIANCE**

STANDARD	CONDITIONS
IEC 61000-4-2, level 4 (ESD)	>15 kV (air); >8 kV (contact discharge)
HBM MIL-Std 883, class 3	>4 kV

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	all diodes loaded	370	K/W
R <sub>th j-s</sub>	thermal resistance from junction to	one diode loaded	135	K/W
	solder point; note 1	all diodes loaded	125	K/W

### Note

1. Solder point of common anode (pin 2).

# Quadruple low capacitance ESD suppressor

### BZA900AVL series

### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 200 mA	_	_	1.2	V
I <sub>R</sub>	reverse current					
	BZA956AVL	$V_R = 3 V$	_	_	200	nA
	BZA962AVL	$V_R = 4 V$	_	_	100	nA
	BZA968AVL	$V_R = 4.3 \text{ V}$	_	_	20	nA
V <sub>Z</sub>	working voltage	I <sub>Z</sub> = 1 mA				
	BZA956AVL		5.32	5.6	5.88	V
	BZA962AVL		5.89	6.2	6.51	V
	BZA968AVL		6.46	6.8	7.14	V
r <sub>dif</sub>	differential resistance	$I_Z = 1 \text{ mA}$				
	BZA956AVL		_	_	200	Ω
	BZA962AVL		_	_	150	Ω
	BZA968AVL		_	_	100	Ω
Sz	temperature coefficient	$I_Z = 1 \text{ mA}$				
	BZA956AVL		_	1.3	_	mV/K
	BZA962AVL		_	2.4	_	mV/K
	BZA968AVL		_	2.9	_	mV/K
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0				
	BZA956AVL		_	22	28	pF
	BZA962AVL		_	18	22	pF
	BZA968AVL		_	16	19	pF
	diode capacitance	f = 1 MHz; V <sub>R</sub> = 5 V				
	BZA956AVL		_	12	17	pF
	BZA962AVL		_	9	12	pF
	BZA968AVL		_	8	11	pF
I <sub>ZSM</sub>	non-repetitive peak reverse current	t <sub>p</sub> = 1 ms; T <sub>amb</sub> = 25 °C				
	BZA956AVL		_	_	0.90	Α
	BZA962AVL		_	_	0.85	Α
	BZA968AVL		_	_	0.80	Α

# Quadruple low capacitance ESD suppressor

### BZA900AVL series

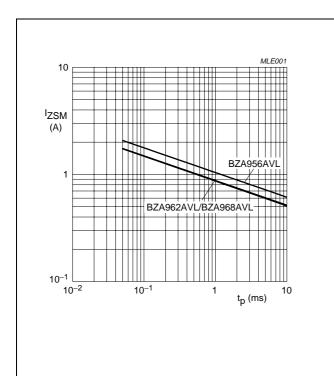


Fig.2 Maximum non-repetitive peak reverse current as a function of pulse time.

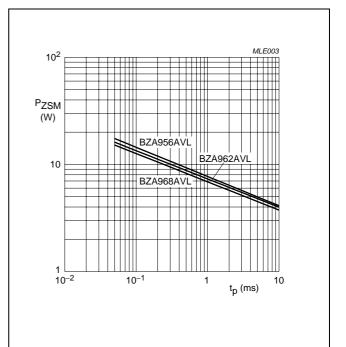
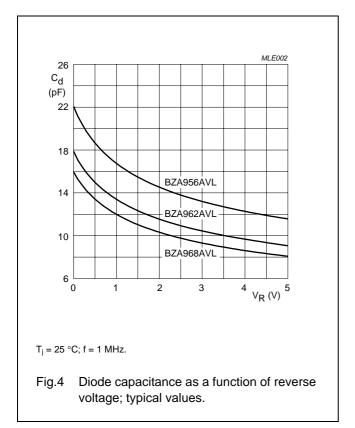
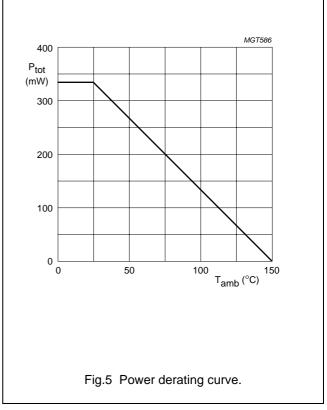


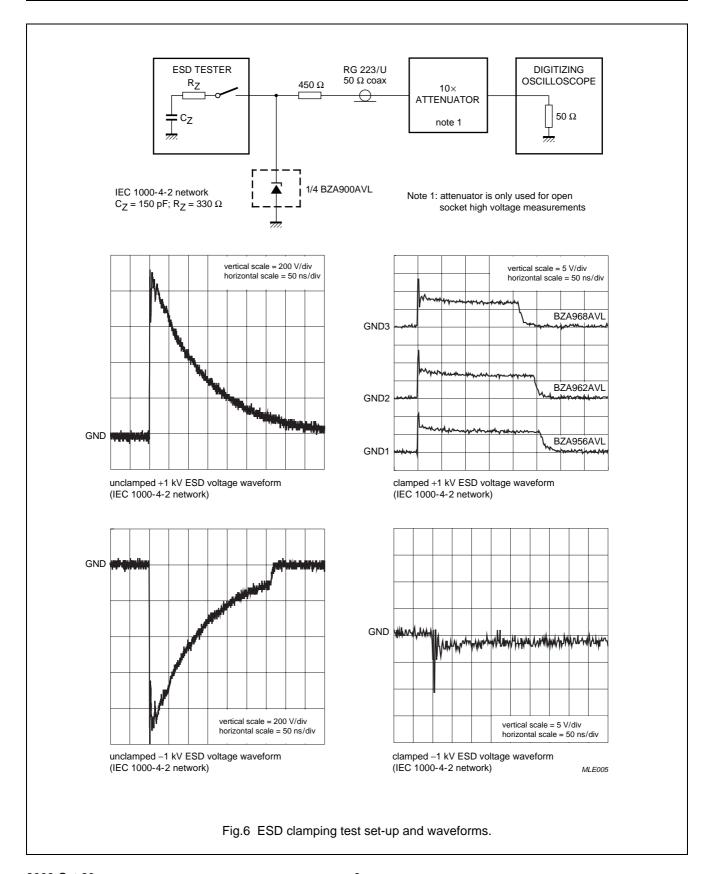
Fig.3 Maximum non-repetitive peak reverse power dissipation as a function of pulse duration (square pulse).





# Quadruple low capacitance ESD suppressor

### BZA900AVL series



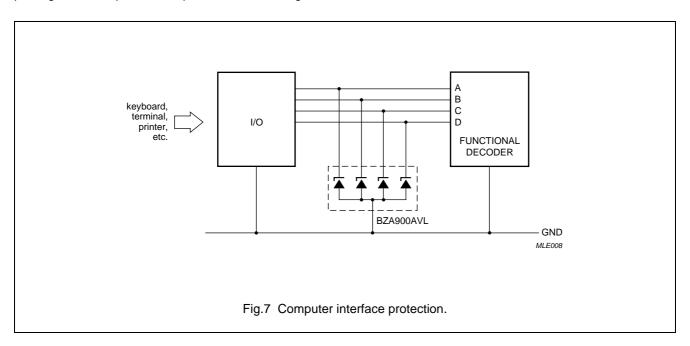
# Quadruple low capacitance ESD suppressor

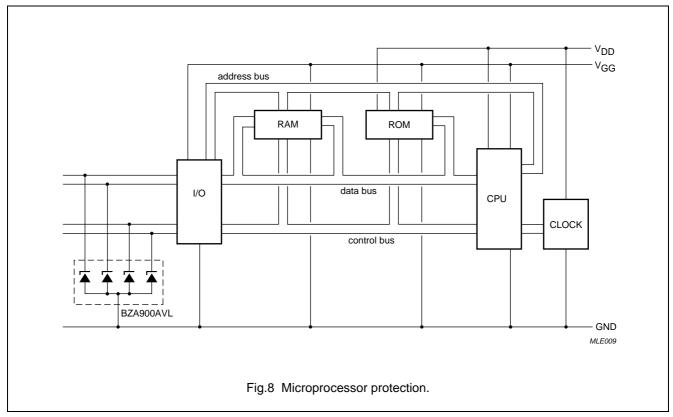
BZA900AVL series

#### **APPLICATION INFORMATION**

### Typical common anode application

A quadruple transient suppressor in a SOT665 package makes it possible to protect four separate lines using only one package. Two simplified examples are shown in Figs.7 and 8.





# Quadruple low capacitance ESD suppressor

BZA900AVL series

### Device placement and printed-circuit board layout

Circuit board layout is of extreme importance in the suppression of transients. The clamping voltage of the BZA900AVL is determined by the peak transient current and the rate of rise of that current (di/dt). Since parasitic inductances can further add to the clamping voltage (V = L di/dt) the series conductor lengths on the printed-circuit board should be kept to a minimum. This includes the lead length of the suppression element.

In addition to minimizing conductor length the following printed-circuit board layout guidelines are recommended:

- 1. Place the suppression element close to the input terminals or connectors
- 2. Keep parallel signal paths to a minimum
- Avoid running protection conductors in parallel with unprotected conductors
- 4. Minimize all printed-circuit board loop areas including power and ground loops
- Minimize the length of the transient return path to ground
- 6. Avoid using shared transient return paths to a common ground point.

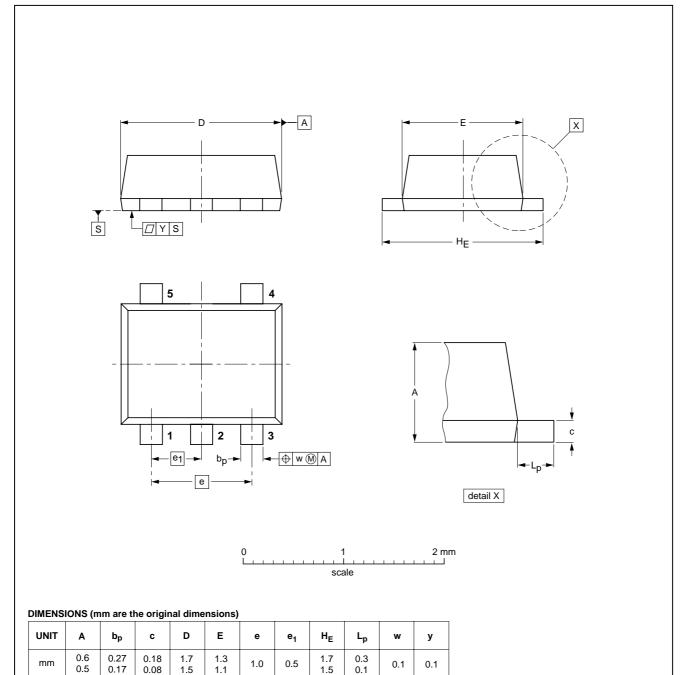
## Quadruple low capacitance ESD suppressor

### BZA900AVL series

### **PACKAGE OUTLINE**

Plastic surface mounted package; 5 leads

**SOT665** 



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT665						<del>-01-01-04</del> 01-08-27

1.5

2003 Oct 20 9

0.17

0.08

# Quadruple low capacitance ESD suppressor

### BZA900AVL series

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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